

# Selective Recognition of Hydrogen Sulfide using Template and Catalyst Free Grown ZnO Nanorods

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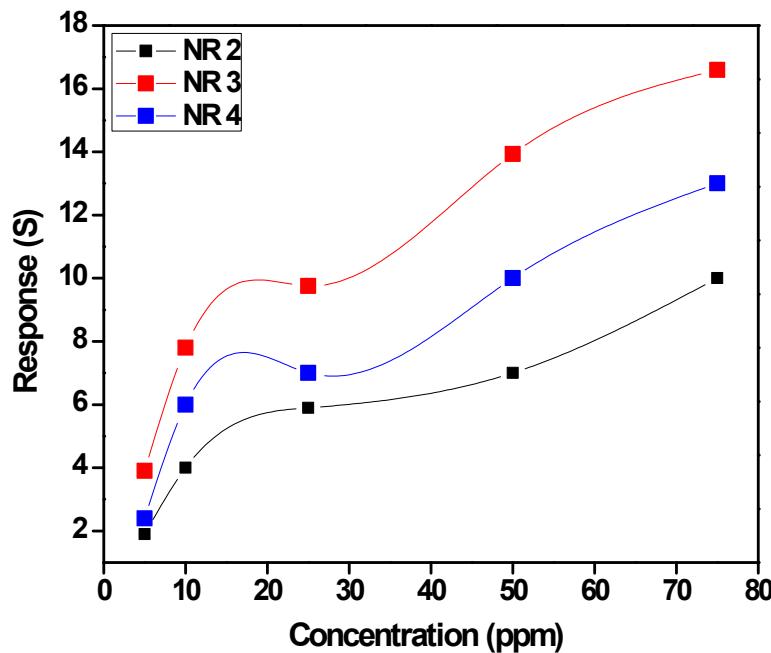
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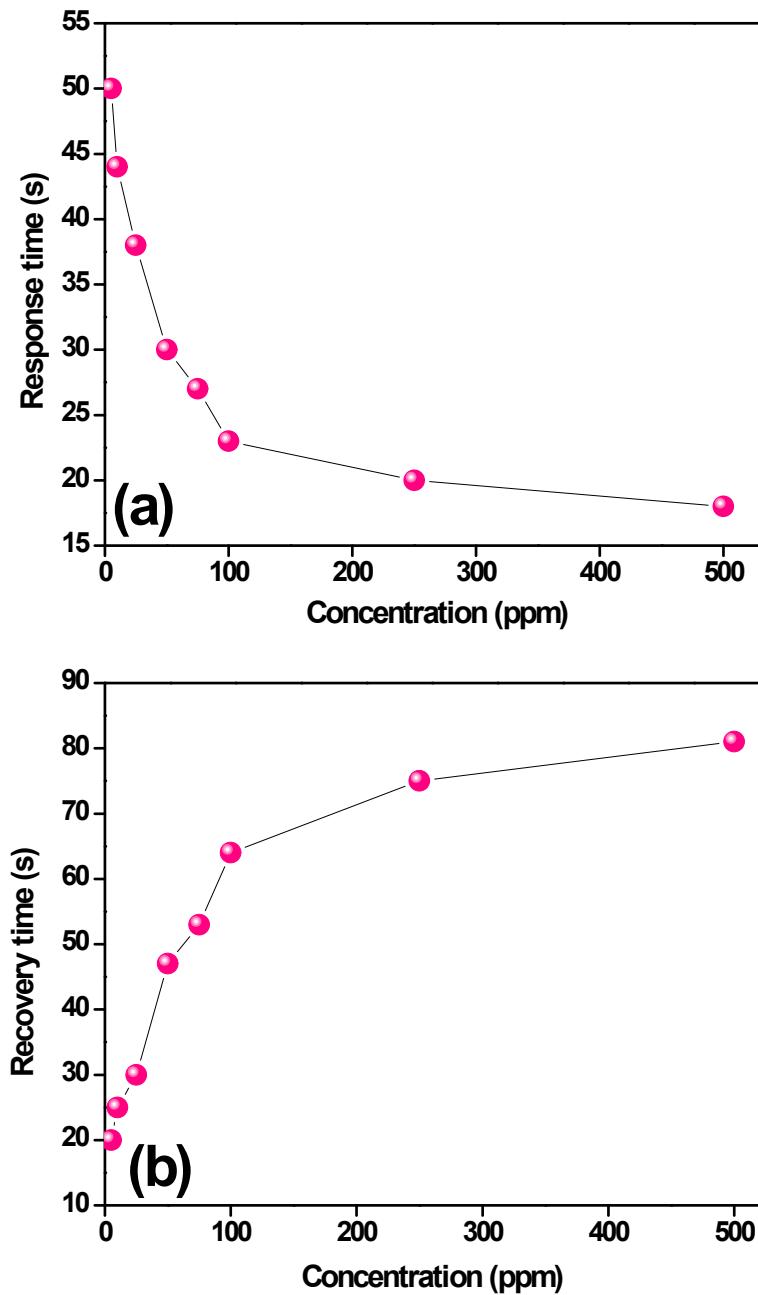
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## Supplementary Files

**Figure S1** Enlarged view of lower concentration sensing response,



**Figure S2: a) Response and b) recovery time characteristics of NR 3 sample with respect to various concentration levels.**



**Table S1**

<b>Material</b>	<b>Structure</b>	<b>Operating temperature (°C)</b>	<b>Concentration (ppm)</b>	<b>Response</b>	<b>Response time (s)</b>	<b>Recovery time (s)</b>	<b>Ref.</b>
<b>CuO-SnO<sub>2</sub></b>	Thin film	150	20	7341	14	118	(Chowdhuri et al., 2002)
<b>ZnO</b>	Single nanowire	RT	300	10	-	-	(Liao et al., 2007)
<b>ZnO</b>	Dendrites	RT	100	17.3	15	30	(Zhang et al., 2008)
<b>ZnO</b>	Porous	332	50	~ 200	6	10	(Liu et al., 2009)
<b>In-doped ZnO</b>	Thin film	250	1000	13000	2	240	(Badadhe and Mulla, 2009)
<b>β-AgVO<sub>3</sub></b>	Nanowire	250	300	1.10	3	17	(Mai et al., 2010)
<b>CuO-ZnO</b>	Hollow spheres	336	5	32.4	47	-	(S. J. Kim et al., 2012)
<b>α-Fe<sub>2</sub>O<sub>3</sub></b>	Nanochain	285	5	4.7	8	65	(Ma et al., 2013)
<b>CuO functionalized SnO<sub>2</sub></b>	Nanowire	300	10	15	9	8	(S. S. Kim et al., 2012)
<b>Zn<sub>2</sub>SnO<sub>4</sub></b>	Microcrystals	270	50	45	10	25	(Ma et al., 2012)

<b>PVA-In<sub>2</sub>O<sub>3</sub></b>	Nanocrystals	38	10	3	25	410	(Singhal et al., 2012)
<b>NiO@ZnO heterostructure</b>	Nanotubes	215	50	474	50	124	(Xu et al., 2012)
<b>ZnO</b>	Thin film	200	50	0.85	13	24	(Shewale et al., 2013)
<b>Pt doped Tungsten oxide</b>	Nanoneedles	250	30	33	200	480	(Vallejos et al., 2014)
<b>In<sub>2</sub>O<sub>3</sub> @ WO<sub>3</sub></b>	Nanoplates	150	5	63	5.5 min	16 min	(Yin et al., 2014)
<b>In<sub>2</sub>O<sub>3</sub>/ZnO</b>	Nanowire	RT	700	935	100	12 h	(Zang et al., 2014)
<b>Cu doped SnO<sub>2</sub></b>	Nanoporous	180	100	25.3%	10	42	(Zhang et al., 2014)
<b>Mo-doped ZnO</b>	Nanowire	300	5	14.11	-	-	(Woo et al., 2014)
<b>CuO-functionalized ZnO</b>	Nanotetrapods	250	50	17	-	400	(Kaur et al., 2014)
<b>ZnO</b>	Nanoflower	RT	1	296	320	3592	(Hosseini et al., 2015)
<b>ZnO</b>	<b>Nanorods</b>	<b>RT</b>	<b>100</b>	<b>111.42</b>	<b>23</b>	<b>64</b>	<b>Present Work</b>

### **Supplementary Table References**

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